



MS AF
REPLY UNDER *#7/C*
37 C.F.R. § 1.116
EXPEDITED PROCEDURE
EXAMINING GROUP 2816
PATENT
0630-1292P
Amend
HTC
Ext. 2 mos

Do not enter
Nov 08-28-03

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: Sun Min KIM et al. Conf.: 3634
Appl. No.: 10/028,686 Group: 2816
Filed: December 28, 2001 Examiner: Hiep Nguyen
For: CHARGE PUMP CIRCUIT IN SEMICONDUCTOR
MEMORY DEVICE

REPLY AFTER FINAL UNDER 37 C.F.R. § 1.116

MS AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

August 18, 2003
RECEIVED
AUG 18 2003
TC 2800 MAIL ROOM

Sir:

In reply to the Office Action dated March 17, 2003, the due for response having been petitioned to be extended two (2) months to August 17, 2003, the following amendments and remarks are respectfully submitted in connection with the above-identified application.

This reply includes an amended claim set, and three (3) new sheets of drawings and Remarks.

The amendments presented herein comply with the "Revised Amendment Format" as set forth in the Official Gazette Notice dated

Appl. No. 10/028,686

February 25, 2003. In accordance with the Notice, the provisions of 37 C.F.R. § 1.121(a)-(d) are waived.